TinyLogic ULP-A Dual 2-Input NAND Gate

NC7WP00

The NC7WP00 is a dual 2-input NAND gate in tiny footprint packages. The device is designed to operate for $V_{CC} = 0.9 \text{ V}$ to 3.6 V.

Features

- Designed for 0.9 V to 3.6 V V_{CC} Operation
- 2.1 ns t_{PD} at 3.3 V (Typ)
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 2.6 mA at 3.3 V
- Available in US8 and MicroPak™ Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

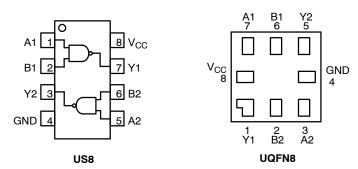


Figure 1. Pinout Diagrams (Top Views)



Figure 2. Logic Symbol



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MARKING DIAGRAMS



UQFN8 1.6X1.6, 0.5P CASE 523AY





US8 CASE 846AN



CC, XXXX = Specific Device Code

KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
A = Assembly Site
L = Wafer Lot Number
YW = Assembly Start Week

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

PIN ASSIGNMENT

Pin	US8	UQFN8
1	A1	Y1
2	B1	B2
3	Y2	A2
4	GND	GND
5	A2	Y2
6	B2	B1
7	Y1	A1
8	V _{CC}	V _{CC}

FUNCTION TABLE $(Y = \overline{AB})$

Inp	Output	
Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

NOTE: H = HIGH Logic Level

1

L = LOW Logic Level

MAXIMUM RATINGS

Symbol	Characteristics		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +4.3	V
V _{IN}	DC Input Voltage		-0.5 to +4.3	V
V _{OUT}		re-Mode (High or Low State) Tri-State Mode (Note 1) wer-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +4.3 -0.5 to +4.3	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-50	mA
lout	DC Output Source/Sink Current		±50	mA
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Ground Pin		±50	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	3	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	US8 MicroPak	250 210	°C/W
P _D	Power Dissipation in Still Air	US8 MicroPak	500 595	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Applicable to devices with outputs that may be tri-stated.
 Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A. (Machine Model) be discontinued.
- 4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Positive DC Supply Voltage		0.9	3.6	V
V _{IN}	DC Input Voltage		0	3.6	V
V _{OUT}	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	0 0 0	V _{CC} 3.6 3.6	
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Transition Rise and Fall Time	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

				T	A = 25°	С	T _A = -40°0	C to +85°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V_{IH}	High-Level Input		0.9	_	0.5	_	-	-	V
	Voltage		1.1 to 1.3	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	
			1.4 to 1.6	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	
			1.65 to 1.95	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	
			2.3 to 2.7	1.6	-	-	1.6	-	
			3.0 to 3.6	2.1	_	-	2.1	-	
V _{IL}	Low-Level Input		0.9	-	0.5	-	-	-	V
	Voltage		1.1 to 1.3	-	-	0.35 x V _{CC}	-	0.35 x V _{CC}	
			1.4 to 1.6	-	_	0.35 x V _{CC}	-	0.35 x V _{CC}	
			1.65 to 1.95	-	_	0.35 x V _{CC}	-	0.35 x V _{CC}	
			2.3 to 2.7	-	_	0.7	-	0.7	
			3.0 to 3.6	-	_	0.9	-	0.9	
V _{OH}	High-Level Output	$V_{IN} = V_{IH}$ or V_{IL}							V
	Voltage	I _{OH} = -20 μA	0.9	-	V _{CC} - 0.1	-	-	-	
			1.1 to 1.3	V _{CC} - 0.1	_	-	V _{CC} - 0.1	-	
			1.4 to 1.6	V _{CC} - 0.1	-	-	V _{CC} - 0.1	-	
			1.65 to 1.95	V _{CC} - 0.1	-	-	V _{CC} - 0.1	-	
			2.3 to 2.7	V _{CC} - 0.1	_	-	V _{CC} - 0.1	-	
			3.0 to 3.6	V _{CC} - 0.1	_	_	V _{CC} - 0.1	-	
		$I_{OH} = -0.5 \text{ mA}$	1.1 to 1.3	0.75 x V _{CC}	-	-	0.70 x V _{CC}	-	
		I _{OH} = -1 mA	1.4 to 1.6	1.07	_	-	0.99	-	
		I _{OH} = -1.5 mA	1.65 to 1.95	1.24	-	-	1.22	-	
		I _{OH} = -2.1 mA	2.3 to 2.7	1.95	_	_	1.87	-	
		$I_{OH} = -2.6 \text{ mA}$	3.0 to 3.6	2.61	-	-	2.55	-	
V_{OL}	Low-Level Output	$V_{IN} = V_{IH}$ or V_{IL}							V
	Voltage	I _{OL} = 20 μA	0.9	_	0.1	_	-	-	
			1.1 to 1.3	-	_	0.1	-	0.1	
			1.4 to 1.6	-	_	0.1	-	0.1	
			1.65 to 1.95	-	_	0.1	-	0.1	
			2.3 to 2.7	-	_	0.1	-	0.1	
			3.0 to 3.6	_	_	0.1	-	0.1	
		I _{OL} = 0.5 mA	1.1 to 1.3	-	_	0.3 x V _{CC}	-	0.3 x V _{CC}	
		I _{OL} = 1 mA	1.4 to 1.6	-	-	0.31	-	0.37	
		I _{OL} = 1.5 mA	1.65 to 1.95	_	_	0.31	-	0.35	
		I _{OL} = 2.1 mA	2.3 to 2.7	-	-	0.31	-	0.33	
		I _{OL} = 2.6 mA	3.0 to 3.6	-	-	0.31	-	0.33	
I _{IN}	Input Leakage Current	V _{IN} = 0 V to 3.6 V	0.9 to 3.6	-	-	±0.1	-	±0.5	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 0 V to 3.6 V or V _{OUT} = 0 V to 3.6 V	0	-	_	0.5	-	0.5	μΑ
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	0.9 to 3.6	-	_	0.9	-	0.9	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

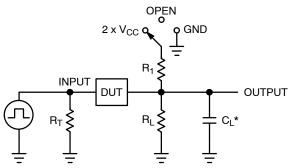
AC ELECTRICAL CHARACTERISTICS

				T _A = 25°C T _A		T _A = -40°C	C to +85°C		
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay,	$R_L = 1 \text{ M}\Omega$, $C_L = 10 \text{ pF}$	0.9	-	40.7	-	-	-	ns
	(A or B) to Y (Figures 3 and 4)		1.10 to 1.30	-	10.9	23.5	-	31.0	
	,		1.40 to 1.60	-	5.6	12.0	-	14.0	
			1.65 to 1.95	_	3.7	10.0	-	12.0	
			2.3 to 2.7	-	2.7	7.0	-	8.0	
			3.0 to 3.6	-	2.1	6.0	-	7.0	
t _{PLH} , t _{PHL}	t _{PHL} Propagation Delay, (A or B) to Y (Figures 3 and 4)	or B) to Y	0.9	-	42.2	-	-	-	ns
			1.10 to 1.30	-	11.4	24.9	-	34.0	
	,		1.40 to 1.60	-	6.0	13.0	-	16.0	
			1.65 to 1.95	-	4.0	10.0	-	12.0	
			2.3 to 2.7	-	3.0	7.0	-	8.0	
			3.0 to 3.6	_	2.3	6.0	-	7.0	
t _{PLH} , t _{PHL}	Propagation Delay,	$R_L = 1 \text{ M}\Omega$, $C_L = 30 \text{ pF}$	0.9	-	46.4	-	-	-	ns
	(A or B) to Y (Figures 3 and 4)		1.10 to 1.30	_	13.0	28.9	-	43.0	
			1.40 to 1.60	-	7.3	16.0	-	18.0	1
			1.65 to 1.95	-	5.1	12.0	-	14.0	
			2.3 to 2.7	_	3.7	9.0	-	10.0	
			3.0 to 3.6	-	2.9	7.0	-	9.0	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition	Typical (T _A = 25°C)	Unit
C _{IN}	Input Capacitance	V _{CC} = 0 V	2.0	pF
C _{OUT}	Output Capacitance	V _{CC} = 0 V	4.0	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz, V_{CC} = 0.9 to 3.6 V, V_{IN} = 0 V or V_{CC}	6.0	pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption: P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

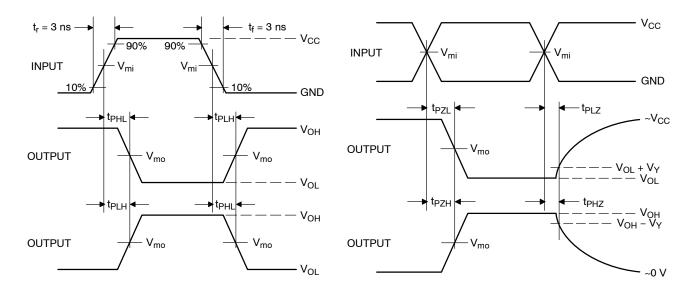


Test	Switch Position
t _{PLH} / t _{PHL}	Open
t _{PLZ} / t _{PZL}	2 x V _{CC}
t _{PHZ} / t _{PZH}	GND

C_L includes probe and jig capacitance

 R_T is Z_{OUT} of pulse generator (typically 50 Ω) f = 1 MHz

Figure 3. Test Circuit



V _{CC} , V	V _{mi} , V	V_{mo}, V	V _Y , V
0.9	V _{CC} / 2	V _{CC} / 2	0.1
1.1 to 1.3	V _{CC} /2	V _{CC} / 2	0.1
1.4 to 1.6	V _{CC} / 2	V _{CC} / 2	0.1
1.65 to 1.95	V _{CC} / 2	V _{CC} / 2	0.15
2.3 to 2.7	V _{CC} / 2	V _{CC} / 2	0.15
3.0 to 3.6	1.5	1.5	0.3

Figure 4. Switching Waveforms

ORDERING INFORMATION

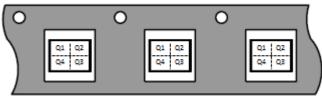
Device	Package	Marking	Pin 1 Orientation (See below)	Shipping [†]
NC7WP00K8X	US8	WP00	Q4	3000 / Tape & Reel
NC7WP00L8X	MicroPak, UQFN8	Y3	Q4	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pin 1 Orientation in Tape and Reel

Direction of Feed

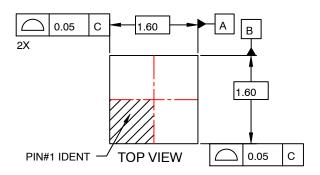


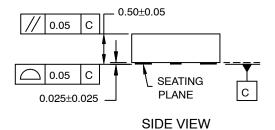


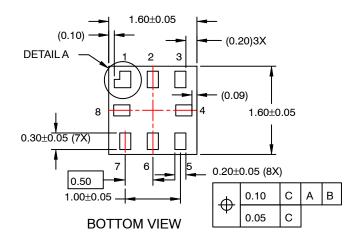
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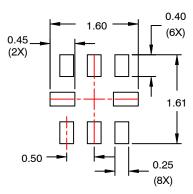
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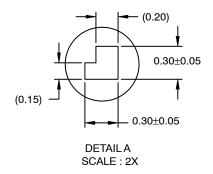




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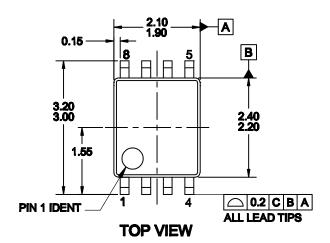


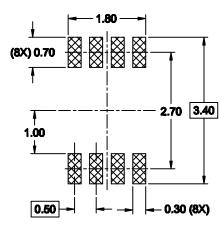
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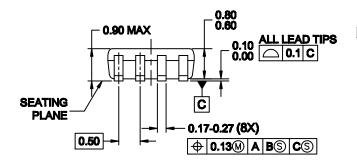
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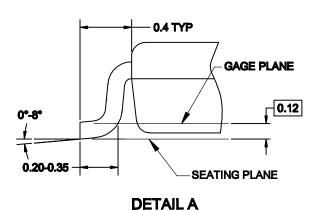
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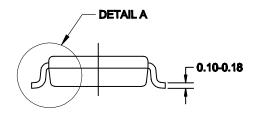


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SIDE VIEW





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